

EC4006

#### **General Description**

The EC4006 is a monolithic constant current white light LED driver using PWM control method. This device consists of internal temperature compensated reference, voltage comparator, controlled duty cycle oscillator with active current limit circuit, driver and high current output switch. This device is specifically designed be used in Step-Down and Step-Up applications with a few external components.

The EC4006 package is SOP-8.

#### **Features**

- Operation input voltage from 3.0V to 36V
- Low Standby Current
- Current Limiting
- Output Switch Current to 0.8A
- Constant output current
- Operation Frequency up to 65KHz (CT=330pF)

#### **Applications**

· White light LED driver



SOP-8

Figure 1. Package Types of EC4006

#### **Ordering Information**

Package	Temperature Range	Part Number	Marking ID	Packing Type
SOP-8	-40 to 85	EC4006M	EC4006M	Tape/Reel

EC4006M is a standard tin-lead product, EC4006M-F means a Lead Free product.

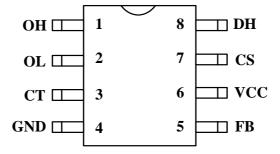
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# EC4006

## **Pin Configuration**

# P / M Package (SOP-8)



**Top View** 

Figure 2. Pin Configuration of EC4006

## **Functional Block Diagram**

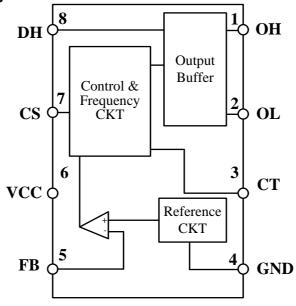


Figure 3. Functional Block Diagram of EC4006



**EC4006** 

**Pin Description** 

Pin Number	Pin Name	Function
1	OH	Output buffer high voltage pin
2	OL	Output buffer low voltage pin
3	СТ	Timing capacitor to control the switching frequency
4	GND	Ground pin for all internal circuits
5	FB	Feedback pin
6	Vcc	Voltage supply
7	CS	Peck current sense Input by monitoring the voltage drop across an external I sense resistor to limit the peak current through the switch
8	DH	Voltage driver output buffer

**Absolute Maximum Ratings (Note 1)** 

Parameter	Symbol	Value	Unit	
Power Supply Voltage	Vcc	40	V	
Driver Collector Current (Note 2)	lc(driver)	100	mA	
Switch Current	lsw	0.8	Α	
Power Dissipation and Thermal Characteristics				
Plastic Package,				
Power Dissipation (TA= 25 )	Pb	1.25	W	
Thermal Resistance	ReJ	100	/W	
SOIC Package, Power Dissipation (TA= 25 ) Thermal Resistance	Pd Røja	625 160	mW /W	
Operating Junction Temperature	TJ	+150		
Storage Temperature Range	Тѕтс	-65 to +150		
ESD (Human body model)		2000	V	

Note1: Stresses greater than those listed under "Absolute Maximum Ratings" may cause permanent damage to thedevice. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "Recommended Operating Conditions" is not implied. Exposure to "Absolute Maximum Ratings" for extended periods may affect device reliability. Note 2: Maximum package power dissipation limits must be observed.

**Recommended Operating Conditions** 

Parameter	Symbol	Min	Max	Unit
Supply Voltage	Vcc	3	36	V
Ambient Temperature	TA	-40	85	

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#### **Electrical Characteristics**

(Vcc = 5.0 V, Ta = -40 to 85, unless otherwise specified.)

			(VCC - 5.0 V, TA40 10 65		, unless otherwise specified.)			
Parameter		Symbol	Conditions		Min	Тур	Max	Unit
OSCILLATOR			1		.1			
Frequency		Fosc	Vpin 5 =0V	CT=1.0nF	24	35	42	KHz
			TA= 25	CT=330pF	50	65	80	KHz
Charge Current		Існ <b>с</b>	Vcc = 5.0 V to 36 V, Ta= 25		24	35	42	μΑ
Discharge Current		IDISCHG	Vcc = 5.0 V to 36 V, Ta= 25		140	220	260	μΑ
Discharge to Charge Current Ratio		IDISCHG/ICHG	Pin 7 to Vcc, Ta= 25		5.2	6.5	7.5	
Current Limit Sense Vo	oltage	VIPK(sense)	ICHG= IDISCHG, TA= 25		250	300	350	mV
OUTPUT BUFFER (No	ote 3)		1			I		
Saturation Voltage		VHL(sat)	IOB= 0.6 A, Pins 1, 8 connected			1.0	1.3	V
Saturation Voltage		VHL(sat)	IOB= 0.6 A, RPin 8 = 82 $\Omega$ to VCC, Forced β= 20			0.45	0.8	V
DC Current Gain		hFE	IOB= 0.6 A, VCE = 5.0 V		50	75		
			Ta= 25					
Output Buffer Off-State Current		IOB(off)	VcE= 36 V			0.01	100	μΑ
COMPARATOR								
Threshold Voltage		Vтн	Ta= 25 Ta= -40 to 85		1.225 1.21	1.250	1.275 1.29	V
Threshold Voltage Regulation	Line	REGLINE	Vcc = 3.0 V t	to 36 V		1.4	5	mV
Input Bias Current		lв	VIN= 0 V			-20	-400	nA
TOTAL DEVICE		1	•		ı	1		
Supply Current		lcc	Vcc= 5.0 V to 36 V, CT = 1.0 nF, Pin 7 = Vcc, Vpin 5 > VTH, Pin 2 = GND, other pins open				4.0	mA

Note 3. Low duty cycle pulse technique is used during test to maintain junction temperature as close to ambient temperature as possible.

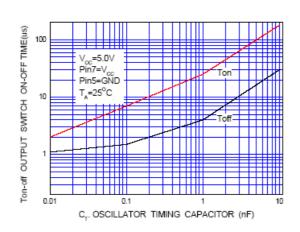
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## **Typical Performance Characteristics**



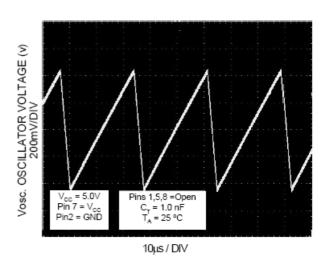
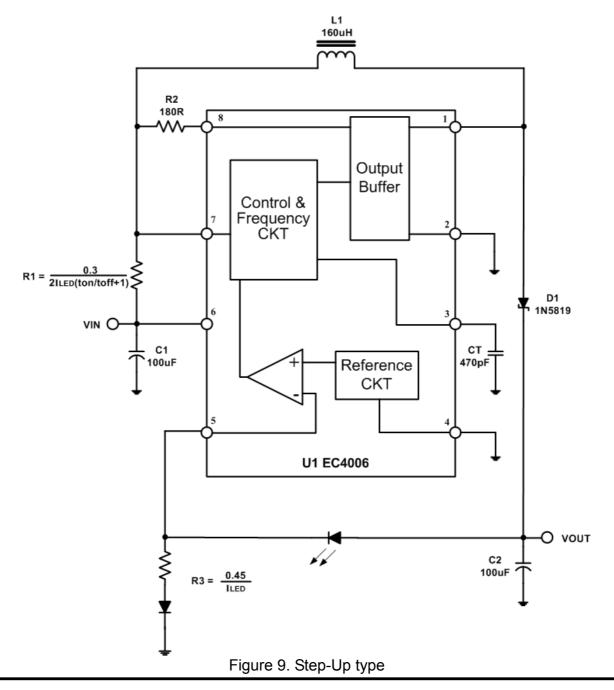


Figure 4. Output Switch On-Off Time vs. Oscillator Timing Capacitor

Figure 5. Timing Capacitor Waveform

# Typical Applications (A) Step-Up type





## (B) Step-Down type

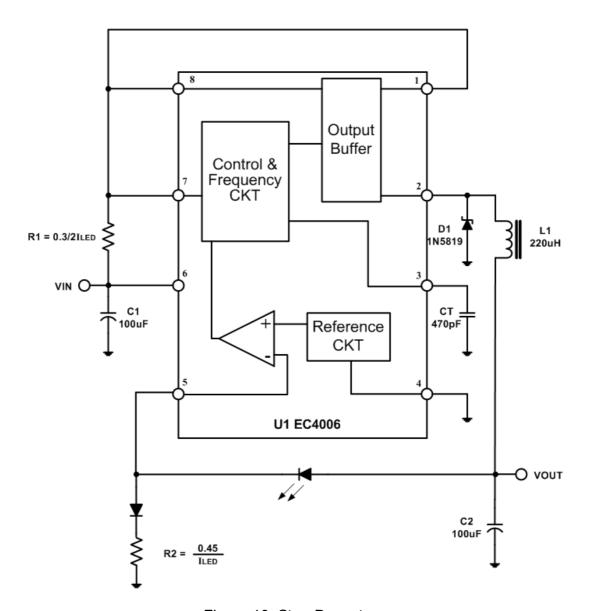


Figure 10. Step-Down type



# **EC4006**

#### **Mechanical Dimensions**

## SOIC-8

